

SHINDENGEN

HVX-2 Series Power MOSFET

N-Channel Enhancement type

**2SK2673
(FP5W90HVX2)**

900V 5A

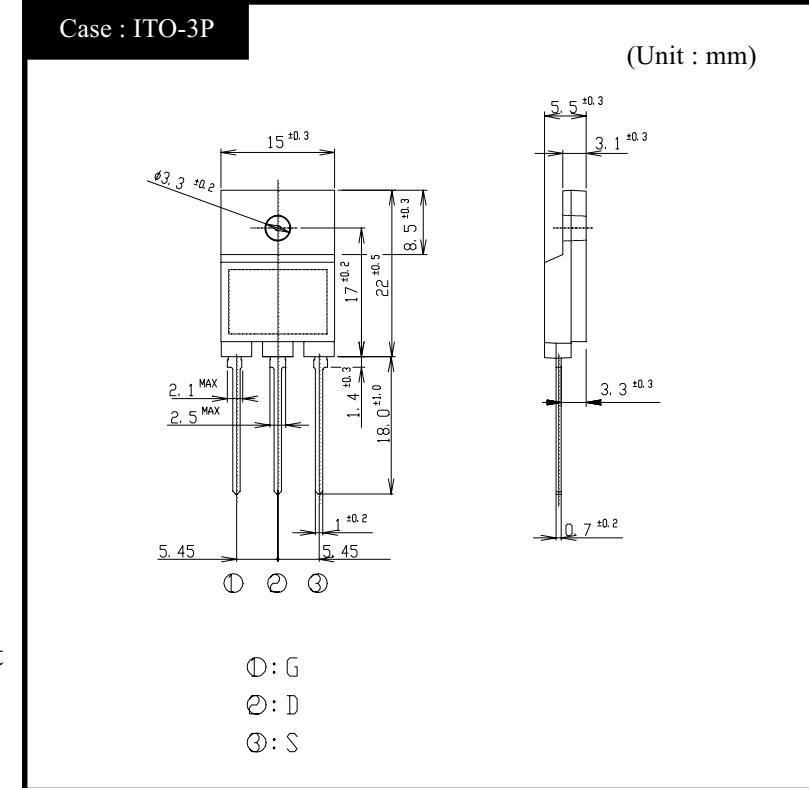
FEATURES

- Input capacitance (C_{iss}) is small.
Especially, input capacitance at 0 bias is small.
- The static $R_{ds(on)}$ is small.
- The switching time is fast.
- Avalanche resistance guaranteed.

APPLICATION

- Switching power supply of AC 240V input
- High voltage power supply
- Inverter

OUTLINE DIMENSIONS



RATINGS

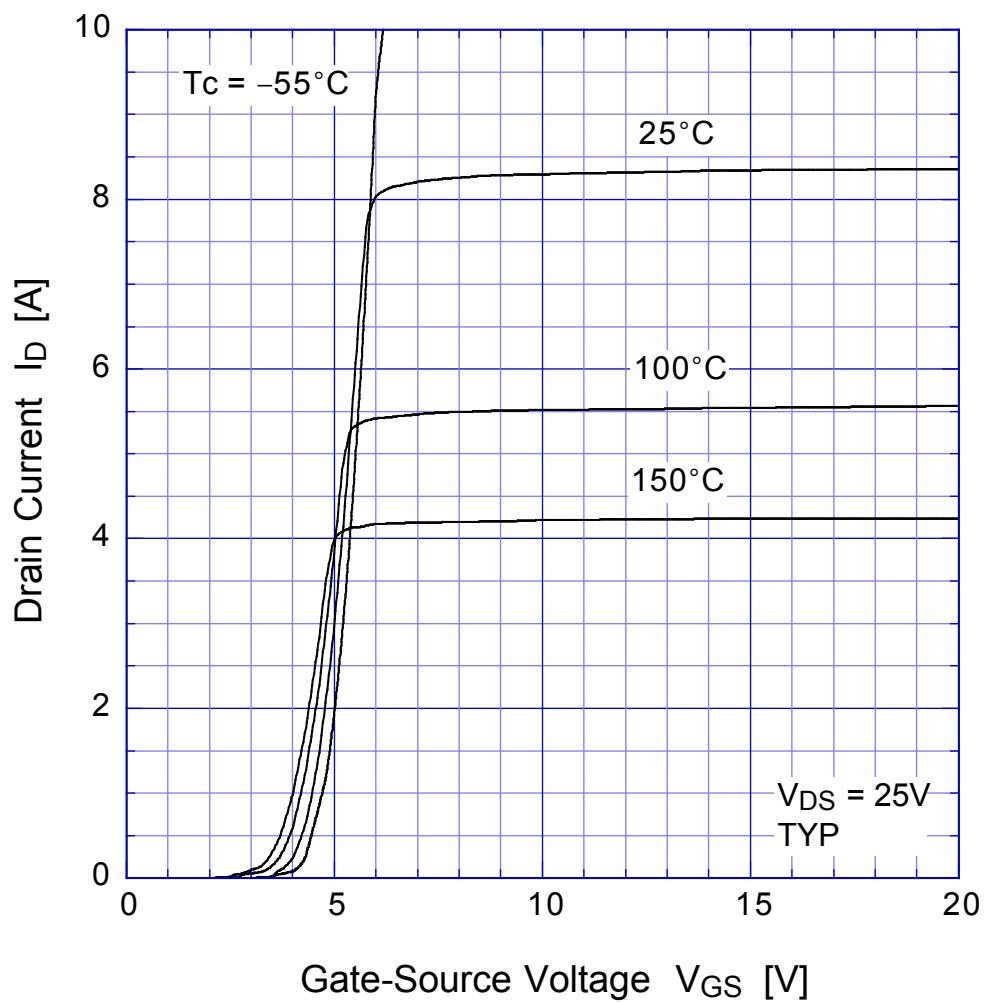
● Absolute Maximum Ratings (T_c = 25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T _{stg}		-55~150	°C
Channel Temperature	T _{ch}		150	
Drain-Source Voltage	V _{DSS}		900	V
Gate-Source Voltage	V _{GSS}		±30	
Continuous Drain Current(DC)	I _D		5	A
Continuous Drain Current(Peak)	I _{DP}	Pulse width≤10 μ s, Duty cycle≤1/100	10	
Continuous Source Current(DC)	I _S		5	
Total Power Dissipation	P _T		50	
Repetitive Avalanche Current	I _{AR}	T _{ch} = 150°C	5	A
Single Avalanche Energy	E _{AS}	T _{ch} = 25°C	100	mJ
Repetitive Avalanche Energy	E _{AR}	T _{ch} = 25°C	10	
Dielectric Strength	V _{dis}	Terminals to case, AC 1 minute	2	kV
Mounting Torque	T _{OR}	(Recommended torque : 0.5 N·m)	0.8	N·m

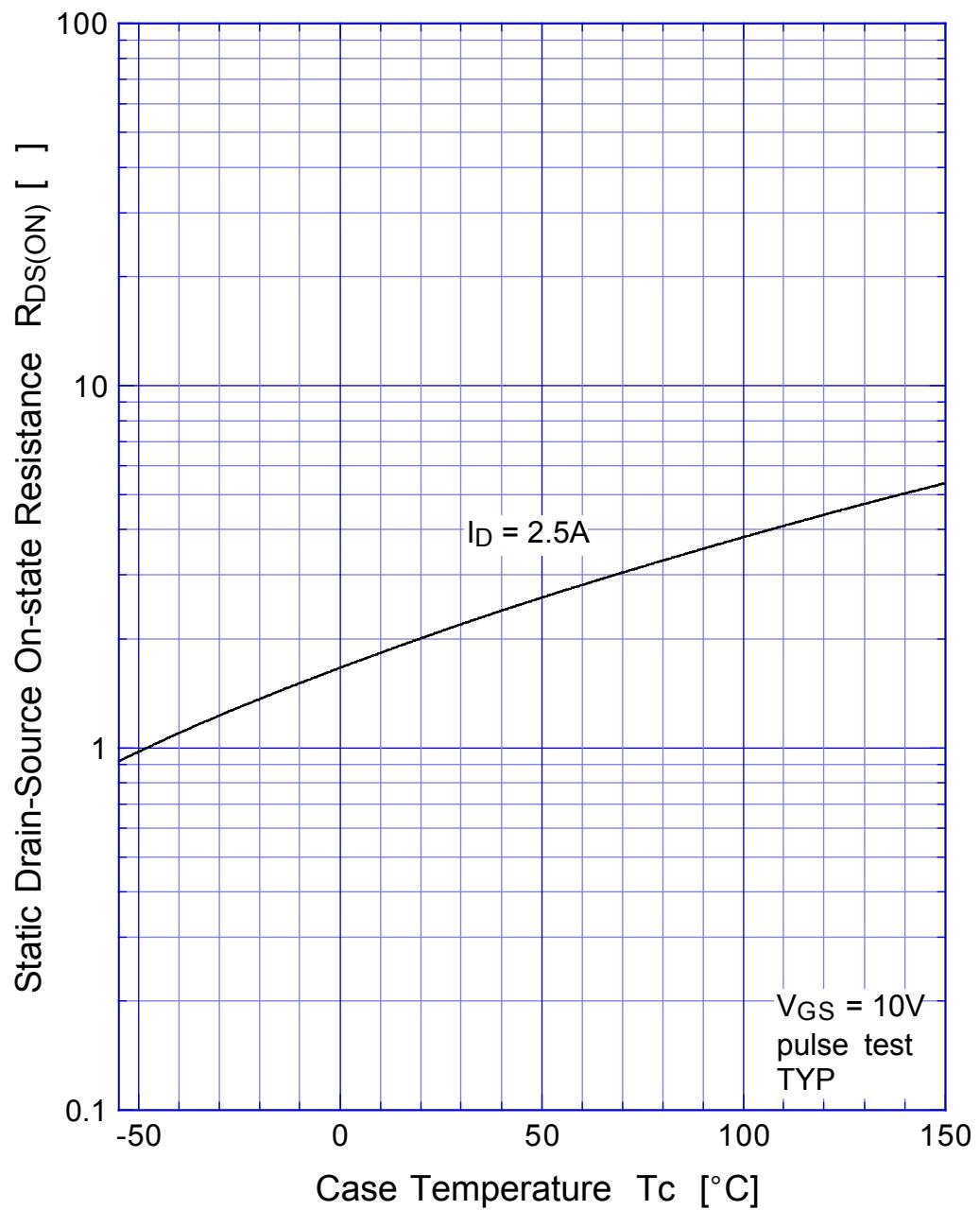
●Electrical Characteristics T_c = 25°C

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	V _{(BR)DSS}	ID = 1mA, V _{GS} = 0V	900			V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 900V, V _{GS} = 0V			250	μA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = ±30V, V _{DS} = 0V			±0.1	
Forward Transconductance	g _{fs}	ID = 2.5A, V _{DS} = 10V	2.4	4.0		S
Static Drain-Source On-state Resistance	R _{DSON}	ID = 2.5A, V _{GS} = 10V		2.1	2.8	Ω
Gate Threshold Voltage	V _{TH}	ID = 1mA, V _{DS} = 10V	2.5	3.0	3.5	V
Source-Drain Diode Forward Voltage	V _{SD}	I _S = 2.5A, V _{GS} = 0V			1.5	
Thermal Resistance	θ _{jc}	junction to case			2.5	°C/W
Total Gate Charge	Q _g			45		nC
Input Capacitance	C _{iss}	V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		1140		pF
Reverse Transfer Capacitance	C _{rss}			23		
Output Capacitance	C _{oss}			105		
Turn-On Time	t _{on}	ID = 2.5A, RL = 60Ω, V _{GS} = 10V		55	100	ns
Turn-Off Time	t _{off}			210	350	

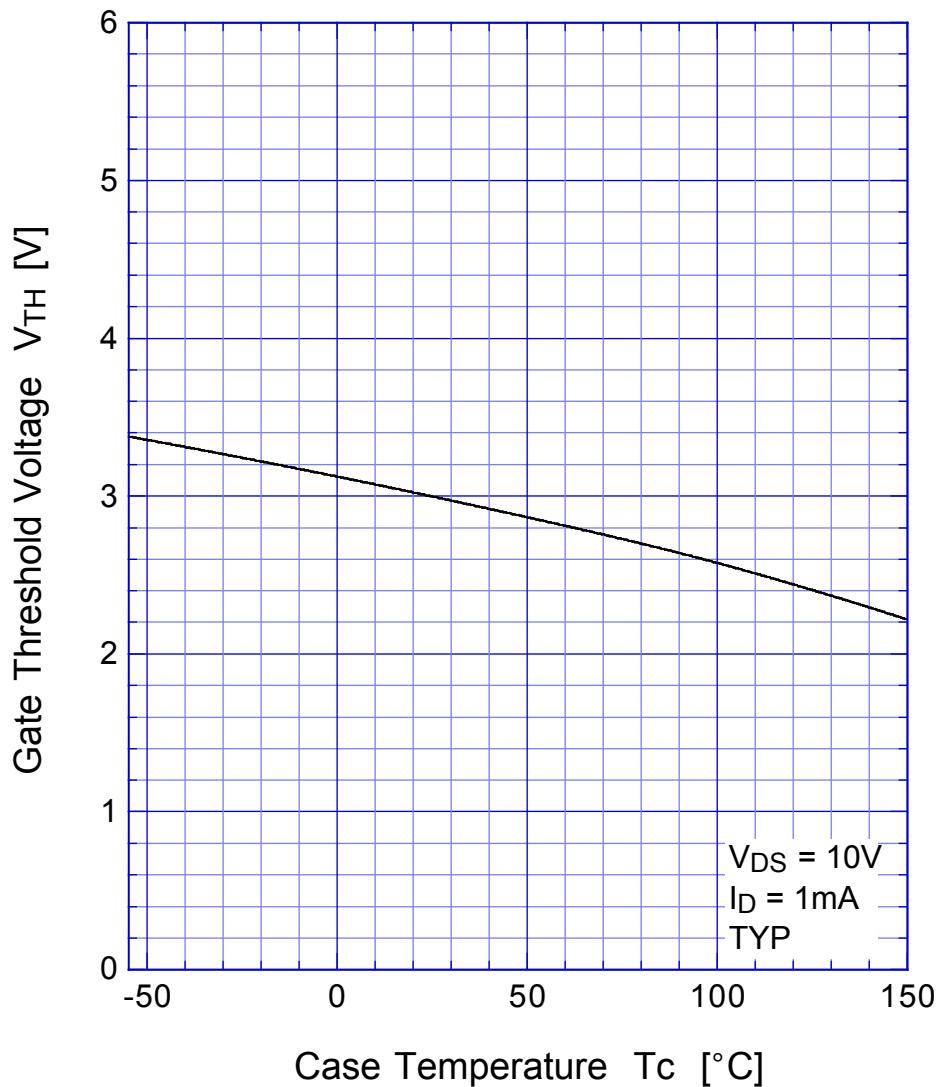
2SK2673 Transfer Characteristics



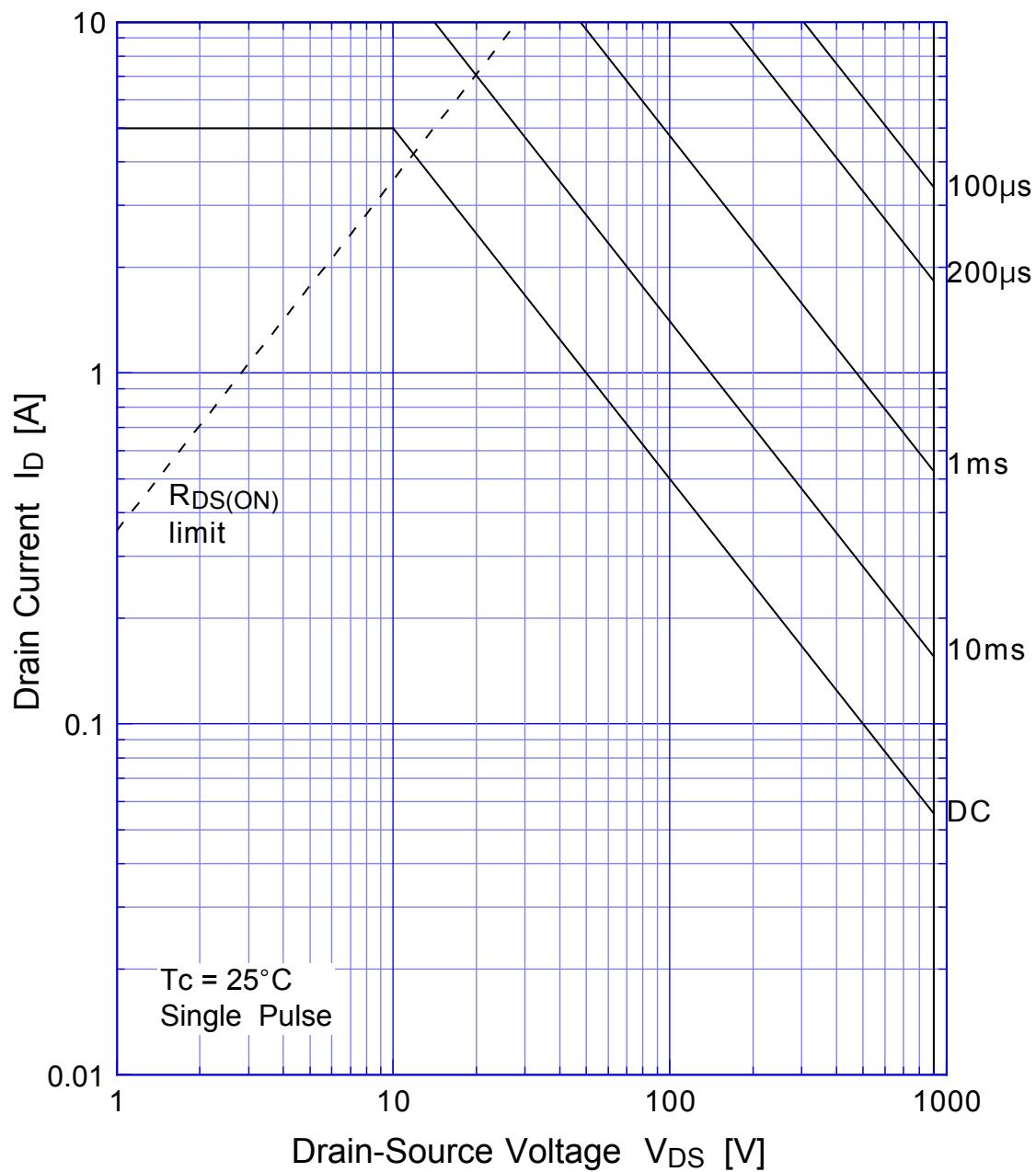
2SK2673 Static Drain-Source On-state Resistance



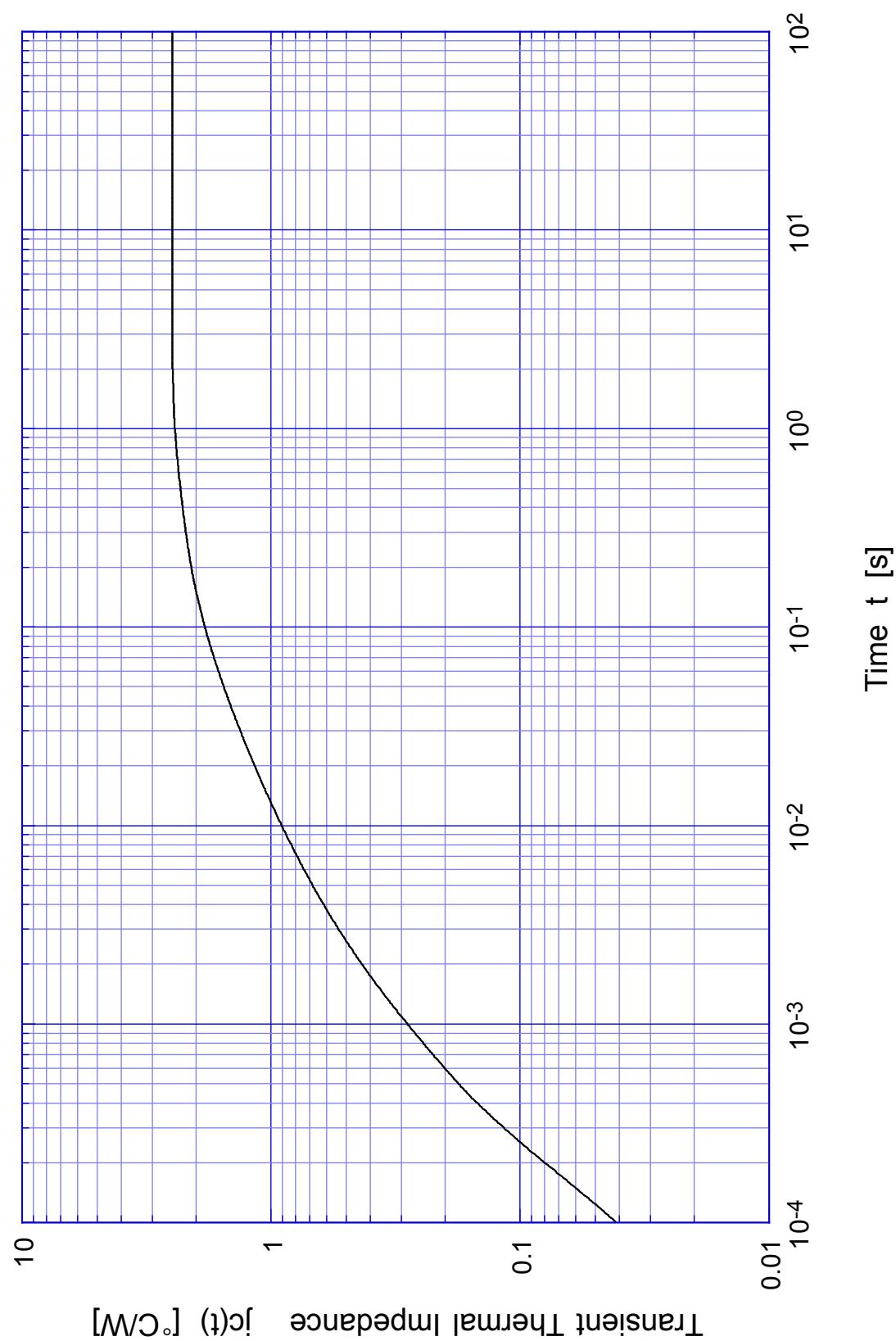
2SK2673 Gate Threshold Voltage



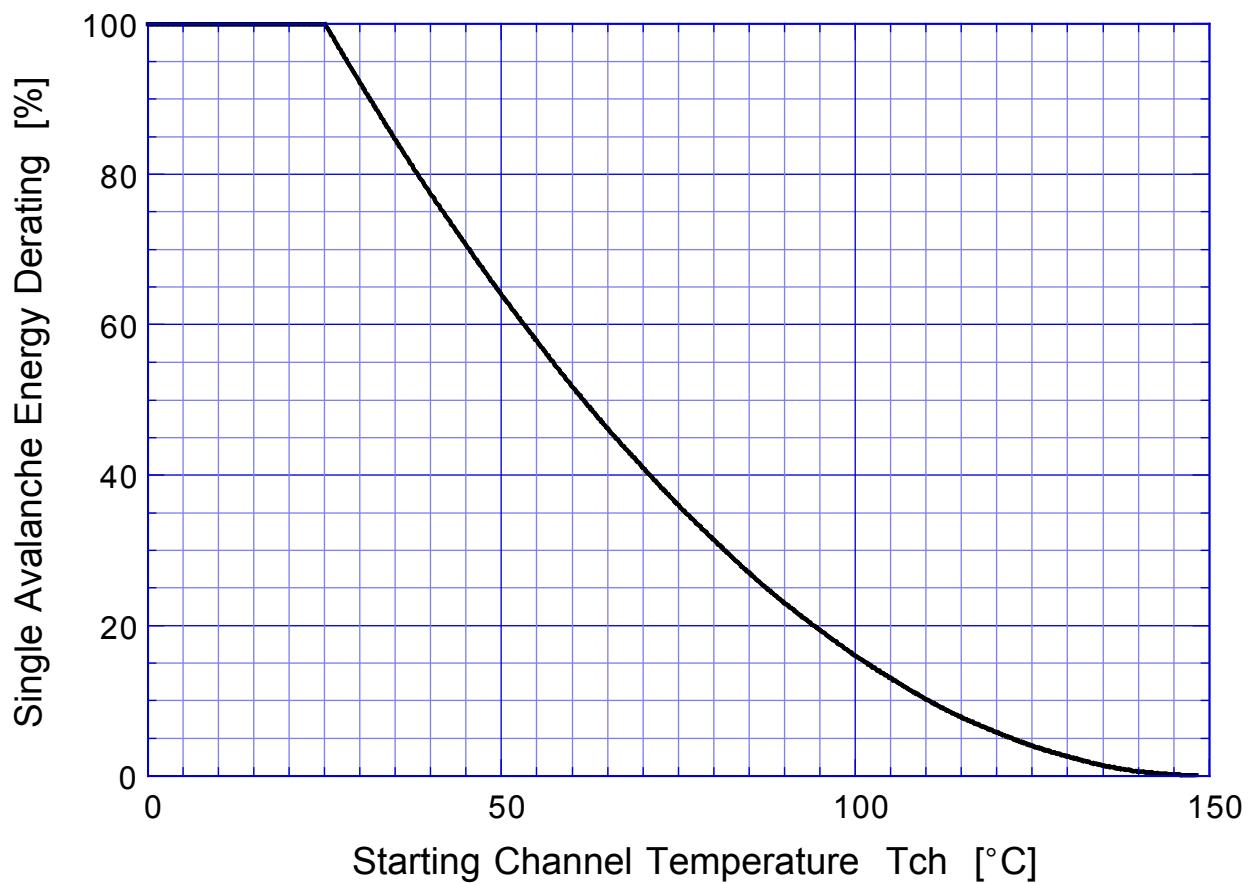
2SK2673 Safe Operating Area



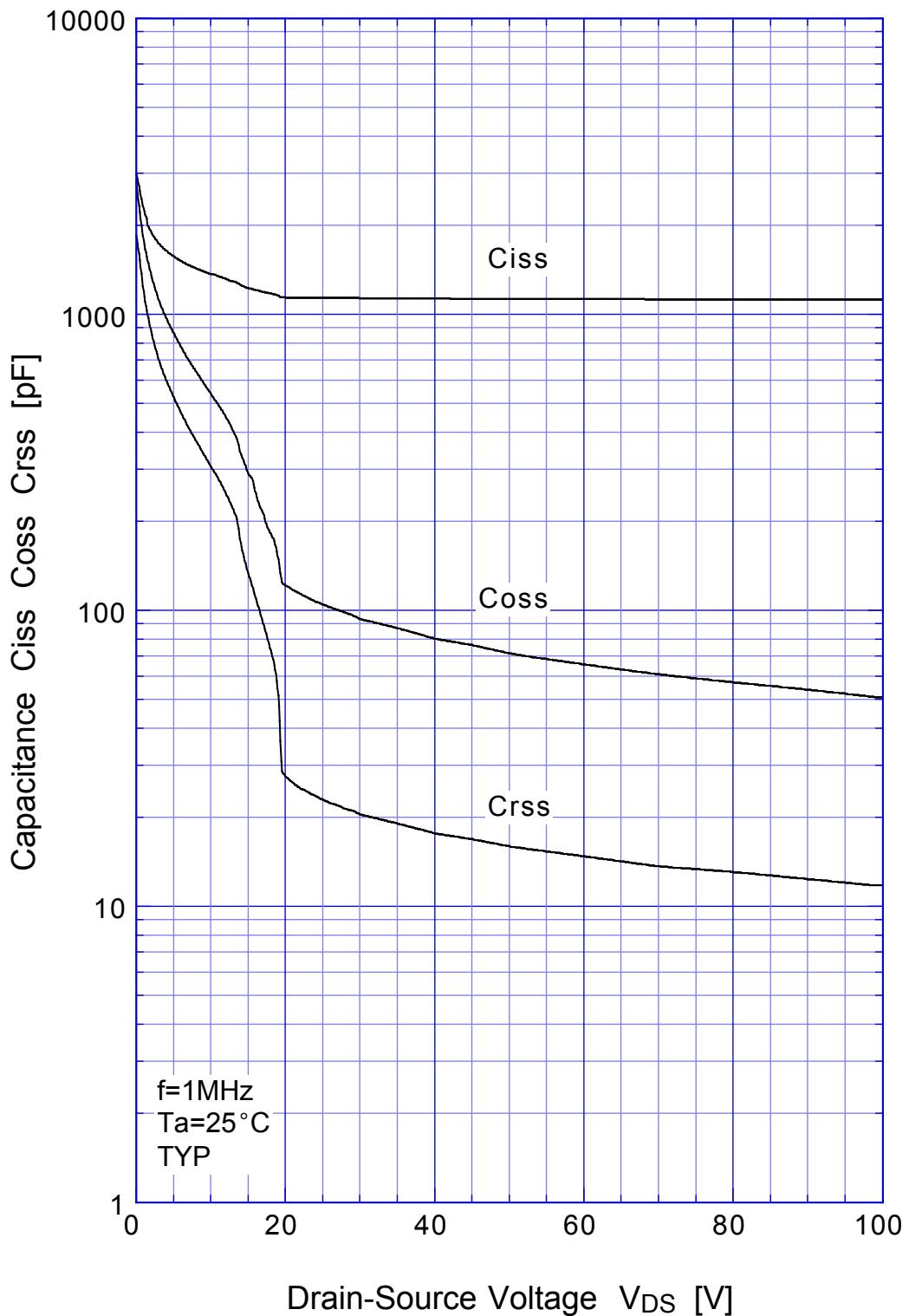
2SK2673 Transient Thermal Impedance



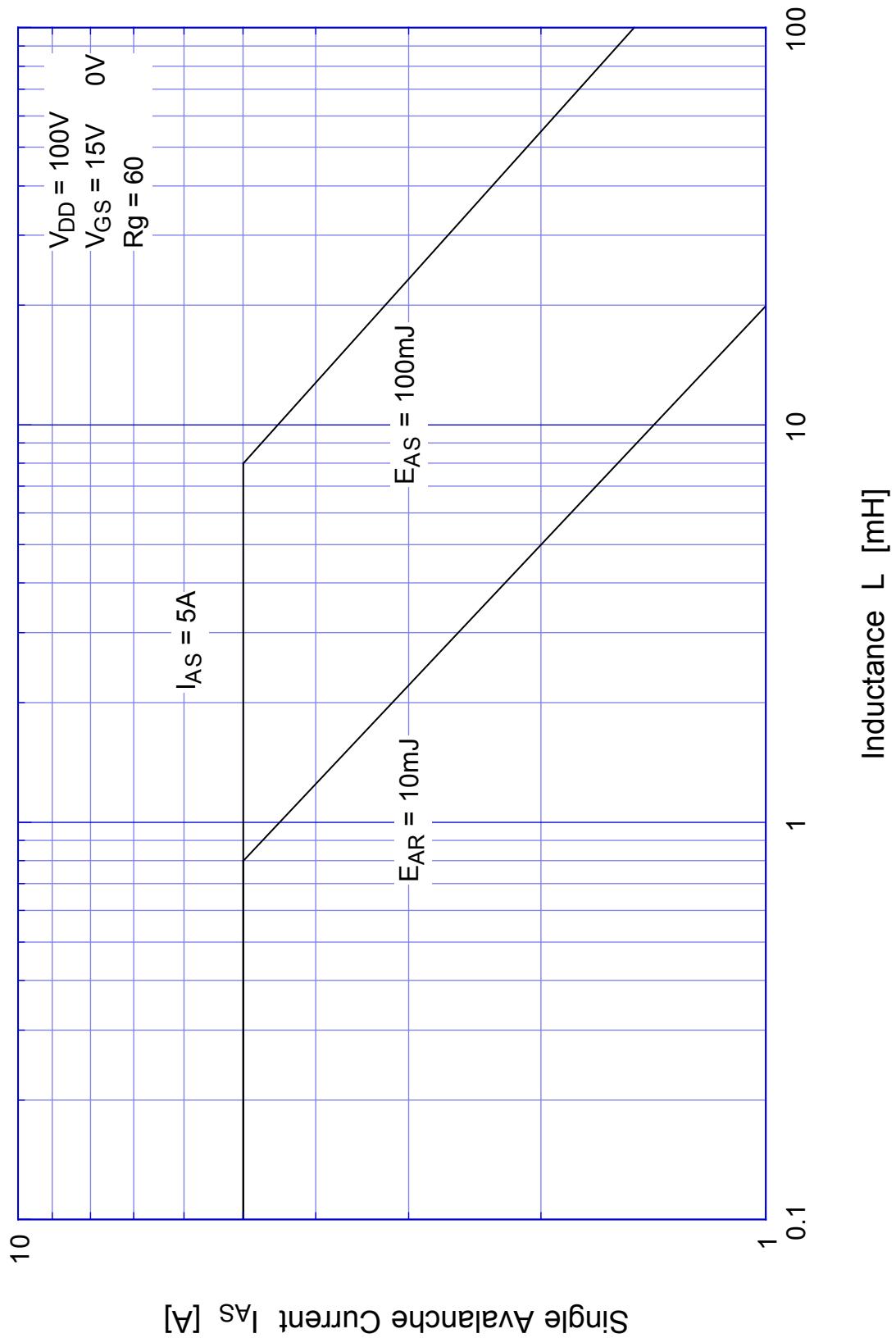
2SK2673 Single Avalanche Energy Derating



2SK2673 Capacitance

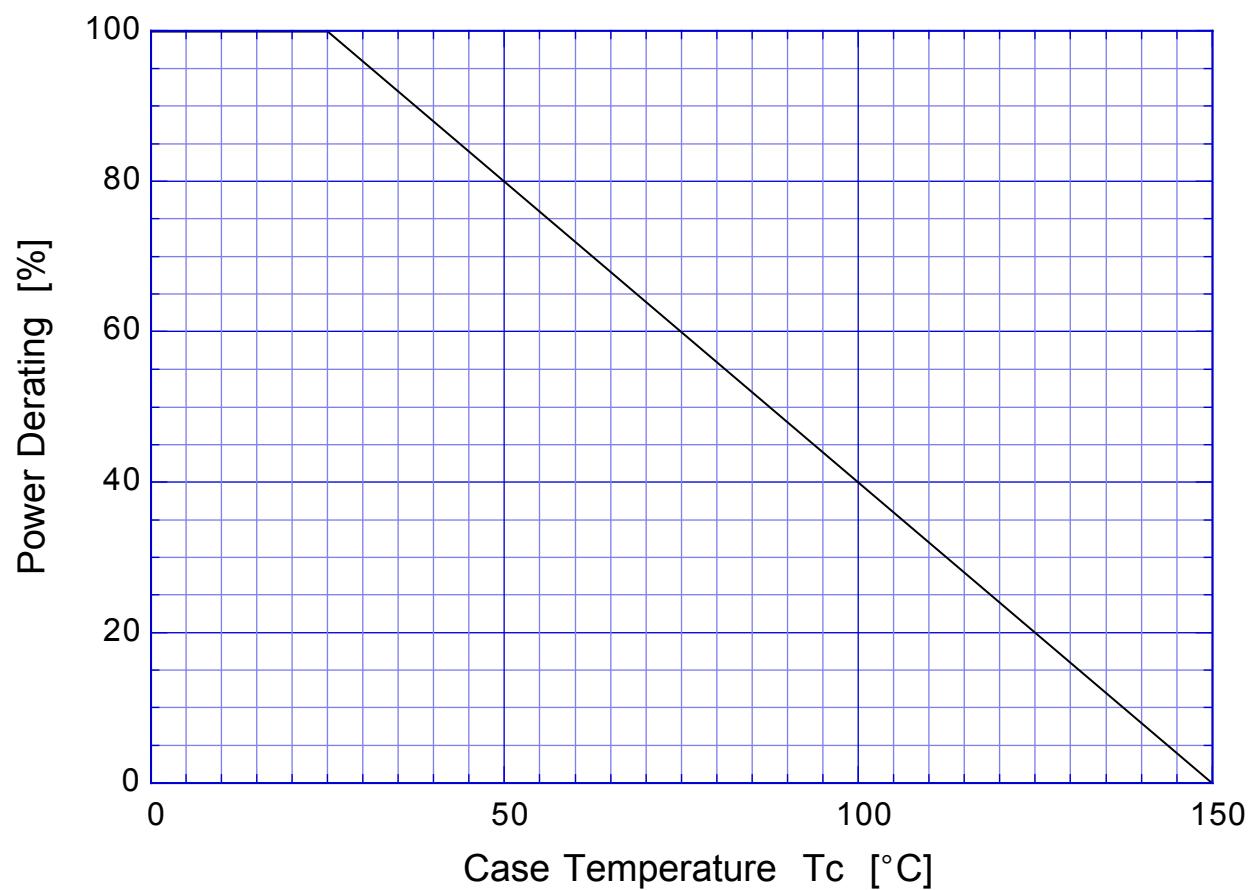


2SK2673 Single Avalanche Current - Inductive Load



2SK2673

Power Derating



2SK2673

Gate Charge Characteristics

